## Zitterbewegung and its effects on electrons in semiconductors

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An analogy between the band structure of narrow gap semiconductors and the Dirac equation for relativistic electrons in vacuum is used to demonstrate that semiconductor electrons experience a Zitterbewegung (trembling motion). Its frequency is  $\omega_Z \approx \mathcal{E}_g/\hbar$  and its amplitude is  $\lambda_Z$ , where  $\lambda_Z = \hbar/m_0^* u$  corresponds to the Compton wavelength in vacuum ( $\mathcal{E}_g$  is the energy gap,  $m_0^*$  is the effective mass, and  $u \approx 1.3 \times 10^8$  cm/s). Once the electrons are described by a two-component spinor for a specific energy band there is no Zitterbewegung but the electrons should be treated as extended objects of size  $\lambda_Z$ . The magnitude of  $\lambda_Z$  in narrow gap semiconductors can be as large as 70 Å. Possible consequences of the above predictions are indicated.

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It was noted in the past that the  $E(\mathbf{k})$  relation between the energy E and the wavenumber  $\mathbf{k}$  for electrons in narrow-gap semiconductors (NGS) is analogous to that for relativistic electrons in vacuum.<sup>1-4</sup> The analogy was also shown to hold for the presence of external fields which was experimentally confirmed on InSb.<sup>5</sup> This "semirelativity in semiconductors" is valid for time dependent phenomena as well, so that the cyclotron resonance of conduction electrons in InSb could be interpreted in terms of the time dilatation between a moving electron and an observer.<sup>5</sup> The semirelativistic phenomena appear at electron velocities of  $10^7 - 10^8$  cm/s, much lower than the light velocity c. The reason for this is that the maximum velocity u in semiconductors, which plays the role of cin vacuum, is about  $10^8$  cm/s.

Until presently the semirelativistic considerations for semiconductors were concerned with phenomena related mostly to classical mechanics. The purpose of this contribution is to investigate the quantum domain described by the Hamiltonian for energy bands in NGS, which bears close similarity to the Hamiltonian for relativistic electrons in vacuum. The effects we predict should be much more readily observable in NGS than in vacuum so this investigation is of interest not only for the solid state physics but also for the high energy physics.

We begin with the  $\mathbf{k} \cdot \mathbf{p}$  approach to InSb-type semiconductors.<sup>6</sup> Taking the limit of large spin-orbit energy  $\Delta$ , the resulting dispersion relation for the conduction and the light-hole bands is  $E=\pm E_p$ , where

$$E_{p} = \left[ \left( \frac{\mathcal{E}_{g}}{2} \right)^{2} + \mathcal{E}_{g} \frac{p^{2}}{2m_{0}^{*}} \right]^{1/2}.$$
 (1)

Here  $\mathcal{E}_g$  is the energy gap and  $m_0^*$  is the effective mass at the band edge. This expression is identical to the relativistic relation for electrons in vacuum, with the correspondence:  $\mathcal{E}_g \rightarrow 2m_0c^2$  and  $m_0^* \rightarrow m_0$ . The electron velocity  $\boldsymbol{v}$  in the conduction band described by Eq. (1) reaches the saturation value as p increases. This can be seen directly by calculating  $v_i = \partial E_p / \partial p_i$  and taking the limit of large  $p_i$ , or by using the analogy  $c = (2m_0c^2/2m_0)^{1/2} \rightarrow (\mathcal{E}_g/2m_0^*)^{1/2} = u$ . Taking the experimental parameters  $\mathcal{E}_g$  and  $m_0^*$  we calculate a very similar value of  $u \approx 1.3 \times 10^8$  cm/s for different III-V compounds.

Now we define an important quantity

$$\lambda_Z = \frac{\hbar}{m_0 u},\tag{2}$$

which we call the length of Zitterbewegung for reasons given below. Here we note that it corresponds to the Compton wavelength  $\lambda_c = \hbar/m_0 c$  for electrons in vacuum. Let us suppose that we confine an electron to the dimensions  $\Delta z$  $\approx \lambda_Z/2$ . Then the uncertainty of momentum is  $\Delta p_z \ge \hbar/\Delta z$ and the resulting uncertainty of energy  $\Delta E \approx (\Delta p_z)^2/2m_0^*$  becomes  $\Delta E \ge 2m_0^* u^2 = \mathcal{E}_g$ . Thus the electron confined to  $\Delta z$  $\approx \lambda_Z/2$  has the uncertainty of energy larger than the gap, so that it "does not know" whether it belongs to the conduction or to the valence band.

Next we consider the band Hamiltonian for NGS. It is derived within the model including  $\Gamma_6$  (conduction),  $\Gamma_8$  (light and heavy hole), and  $\Gamma_7$  (split-off) bands and it represents an  $8 \times 8$  operator matrix.<sup>7</sup> We assume, as before,  $\Delta \gg \mathcal{E}_{g}$  and omit the free electron terms since they are negligible for NGS. The resulting  $6 \times 6$  Hamiltonian has  $\pm \mathcal{E}_g/2$  terms on the diagonal and linear  $\hat{p}_i$  terms off the diagonal, just like in the Dirac equation for free electrons. However, the three  $6 \times 6$  matrices  $\hat{\alpha}_i$  multiplying the momentum components  $\hat{p}_i$ do not have the properties of  $4 \times 4$  Dirac matrices, which considerably complicates calculations. For this reason, with only a slight loss of generality, we take  $\hat{p}_z \neq 0$  and  $\hat{p}_x = \hat{p}_y = 0$ . In the  $\hat{\alpha}_3$  matrix, two rows and columns corresponding to the heavy holes contain only zeros and they can be omitted. The remaining Hamiltonian for the conduction and the light hole bands reads

$$\hat{H} = u\hat{\alpha}_3\hat{p}_z + \frac{1}{2}\mathcal{E}_g\hat{\beta},\qquad(3)$$

where  $\hat{\alpha}_3$  and  $\hat{\beta}$  are the well-known 4×4 Dirac matrices.<sup>8</sup> The Hamiltonian (3) has the form appearing in the Dirac equation and in the following we can use the procedures of relativistic quantum mechanics (RQM).

The electron velocity is  $\dot{z} = (1/i\hbar)[z,\hat{H}] = u\hat{\alpha}_3$ . The eigenvalues of  $\hat{\alpha}_3$  are  $\pm 1$ , so that the eigenvalues of  $\dot{z}$  are, paradoxically,  $\pm u$ . In order to determine  $\hat{\alpha}_3(t)$  we calculate  $\dot{\hat{\alpha}}_3(t)$ 

by commuting  $\hat{\alpha}_3$  with  $\hat{H}$  and integrating the result with respect to time. This gives  $\dot{z}(t)$  and we calculate z(t) integrating again. The final result is (cf. Refs. 9 and 10)

$$z(t) = z(0) + \frac{u^2 p_z}{\hat{H}} t + \frac{i\hbar u}{2\hat{H}} \hat{A}_0 \left[ \exp\left(\frac{-2i\hat{H}t}{\hbar}\right) - 1 \right], \quad (4)$$

where  $\hat{A}_0 = \hat{\alpha}_3(0) - up_z/\hat{H}$ . There is  $1/\hat{H} = E_p^{-2}\hat{H}$ . The first two terms of Eq. (4) represent the classical electron motion. The third term describes time dependent oscillations with a frequency of  $\omega_Z \approx \mathcal{E}_g/\hbar$ . Since  $A_0 \approx 1$ , the amplitude of oscillations is  $\hbar u/2\hat{H} \approx \hbar/2m_0^* u = \lambda_Z/2$ . In RQM the analogous oscillations are called Zitterbewegung (ZB, trembling motion), which explains the name given above to  $\lambda_Z$ . We note that the ZB goes beyond Newton's first law since we have a nonconstant velocity without a force. In RQM it is demonstrated that the ZB is a result of interference between states of positive and negative electron energies.

In order to investigate the case of a definite sign of energy, we expand the multiband Hamiltonian of Ref. 7 into an effective one-band Hamiltonian for the  $\Gamma_6$  conduction band (here we assume quite generally  $\hat{\mathbf{p}} \neq 0$ ). We do this by solving the initial set of six equations for the envelope functions (for  $\Delta \gg \mathcal{E}_g$ ) by substitution, i.e., expressing the valence functions  $f_3 \cdots f_6$  by the conduction functions  $f_1$  and  $f_2$  for spin-up and spin-down states, respectively. When doing this we account for the changed normalization condition (see Refs. 11 and 12). The final result is

$$\hat{H} = \frac{\mathcal{E}_g}{2} + V + \frac{P^2}{2m_0^*} + \frac{g^* \mu_B}{2} \boldsymbol{\sigma} \cdot \boldsymbol{B} - \frac{1}{\mathcal{E}_g} \left( \frac{P^2}{2m_0^*} + \frac{g^* \mu_B}{2} \boldsymbol{\sigma} \cdot \boldsymbol{B} \right)^2 + \frac{\hbar}{4\mathcal{E}_g m_0^*} \boldsymbol{\sigma} \cdot (\boldsymbol{\nabla} V \times \boldsymbol{P}) + \frac{\hbar^2}{4\mathcal{E}_g m_0^*} \boldsymbol{\nabla}^2 V,$$
(5)

where  $\mathbf{P}=\mathbf{p}+e\mathbf{A}$  is the canonical momentum, *V* is an external potential,  $\boldsymbol{\sigma}$  is the Pauli spin operator,  $\mu_B$  is the Bohr magneton, **B** is an external magnetic field, and  $g^*$  is the Landé spin factor. The first four terms represent the effective Pauli equation, the fifth is a nonparabolic correction to the energy, the sixth is an effective spin-orbit interaction, and the last one is the effective Darwin term.<sup>13</sup> The Hamiltonian (5) is in relativistic analogy to  $v^2/c^2$  expansion of the Dirac equation, known from RQM (see Ref. 14).

The effective Darwin term can be interpreted in terms of ZB. If an electron oscillates around the position **r**, the potential energy can be expanded as follows:  $V(\mathbf{r}+\Delta \mathbf{r}) \approx V(\mathbf{r}) + \Delta \mathbf{r} \cdot \nabla V + (\Delta \mathbf{r} \cdot \nabla)(\Delta \mathbf{r} \cdot \nabla)V/2$ . On average the odd powers of  $\Delta \mathbf{r}$  vanish and the last term is  $(\Delta \mathbf{r})^2 \nabla^2 V/6$ . It becomes equal to the effective Darwin term in Eq. (5) if  $(\Delta \mathbf{r})^2 = (3/4)\lambda_Z^2$ , which corresponds to  $\Delta z = \lambda_Z/2$ . This is in agreement with our previous arguments. However, once the electron is described by a two-component spinor for a specific energy band, as in Eq. (5), the quantity  $\Delta \mathbf{r}$  is not the amplitude of ZB anymore. We discuss this below.

The four-component wave functions resulting from Eq. (3) can be transformed exactly into two-component functions for positive (or negative) electron energies. For free electrons this is done by applying the Foldy-Wouthuysen (FW) unitary

transformation.<sup>15</sup> In our one-dimensional treatment the transformation reads

$$e^{iS} = \frac{E_p + \hat{\beta}\hat{H}}{[2E_p(E_p + m_0^* u^2)]^{1/2}}.$$
 (6)

The transformed wave functions  $\Psi'(z)$  are obtained from the initial functions  $\Psi(z')$  by the following integration:

$$\Psi'(z) = \int K(z,z')\Psi(z')dz', \qquad (7)$$

where

$$K(z,z') = \frac{1}{2\pi} \int \left(\frac{2E_{p'}}{E_{p'} + m_0^* u^2}\right)^{1/2} \frac{1}{2} \left(1 + \frac{\beta \hat{H}}{E_{p'}}\right) \\ \times \exp\left[\frac{ip'_3(z-z')}{\hbar}\right] dp'_3.$$
(8)

The kernel K(z,z') is not a point transformation. Suppose we are interested in the eigenfunction of position  $\hat{z}$ . In the initial representation this function is  $\Psi(z') = \delta(z'-z_0)$ , and it follows from Eq. (7) that the transformed function is  $K(z,z_0)$ . The integral of  $K(z,z_0)$  over  $Z=z-z_0$  axis is unity. To get an idea of the extension of  $K(z,z_0)$ , we calculate its second moment and after some manipulations we obtain (see Ref. 16)

$$\int Z^2 K(z, z_0) dZ = \frac{1}{4} \lambda_Z^2.$$
(9)

Thus the extension of the transformed eigenfunction of position is  $|z-z_0| \approx \lambda_Z/2$ . One can show that in the transformed state there is no Zitterbewegung since the FW transformation eliminates the negative energy components of the wave functions.<sup>17</sup> All in all, following the interpretation established in RQM, we are confronted with the following choice. (1) We deal with a pointlike electron described by a fourcomponent function, which experiences the ZB with the radius of  $\lambda_Z/2$ . (2) The electron is described by a twocomponent spinor for either positive or negative energy and there is no ZB, but the electron is smeared to an object of the radius  $\lambda_Z/2$ . It is this smearing that enters into the effective Darwin term in Eq. (5), as this equation describes electrons using two-component spinors for positive energies. In other words, the Darwin term is a direct consequence of smearing.

The above result has far reaching consequences. In most cases electrons in a specific band are described by effective band parameters obtained with the use of the Luttinger-Kohn (LK) transformation.<sup>18</sup> In fact, our Eq. (5) can also be obtained by this method. The LK transformation separates energy bands and it corresponds directly to the Foldy-Wouthuysen transformation in RQM. For the FW transformation the expansion parameter is  $S_{FW}=p/2m_0c$  = $k\lambda_c/2$ , while for the LK transformation it is  $S_{LK}$  = $\hbar k/(2m_0^* \mathcal{E}_g)^{1/2} = k\lambda_Z/2$ . Once again we find the correspondence between  $\lambda_c$  and  $\lambda_Z$ . It follows from the above reasoning that electrons in a given energy band described by the one-band effective mass approximation are not point particles, but rather we should attribute to them the effective size  $\lambda_Z$ .

Clearly, the magnitude of  $\lambda_Z$  is essential. There is  $\lambda_Z = \lambda_c(c/u)(m_0/m_0^*) \approx 0.89(m_0/m_0^*)$  Å since, as mentioned above,  $u \approx 1.3 \times 10^8$  cm/s for various materials. We estimate: for GaAs  $(m_0^* \approx 0.067m_0)$   $\lambda_Z \approx 13$  Å, for InAs  $(m_0^* \approx 0.024m_0)$   $\lambda_Z \approx 37$  Å, for InSb  $(m_0^* \approx 0.014m_0)$   $\lambda_Z \approx 64$  Å. Thus in contrast to vacuum ( $\lambda_c = 3.86 \times 10^{-3}$  Å) the length of ZB in semiconductors can be quite large and one can confine electrons to the dimensions of  $\lambda_Z$  using quantum wells, wires, dots, or external fields. For an electron in a magnetic field the magnetic radius is  $L = (\hbar/eB)^{1/2} \approx 80$  Å at B = 10 T, and it is fairly easy to achieve  $L < \lambda_Z$  for NGS.

It may appear unreasonable to ascribe to an electron the size of, say, 70 Å. However, it is well-known that the values of  $1/m_0^*$  and  $g_0^*$  in very narrow gap semiconductors can be 100 times larger than the corresponding values for free electrons. The special property of  $\lambda_Z = \hbar/m_0^* u$  is that it cumulates the largeness of  $1/m_0^*$  and of 1/u for semiconductors, as compared to  $1/m_0$  and 1/c for vacuum.

The Zitterbewegung length  $\lambda_Z$  appears in the description of interband tunneling. The tunneling in vacuum from the Dirac sea of electrons with negative energies to the empty states of electrons with positive energies in the presence of a linear potential V(z) = eFz has been treated by RQM.<sup>19,20</sup> The tunneling probability is proportional to exp(-W), where W  $=\pi m_0^2 c^2 / e\hbar F = (\pi/2)(z_0/\lambda_c)$ , in which  $z_0 = 2m_0 c^2 / eF$  is the tunneling length. This probability becomes appreciable at critical electric fields  $F_{cr}$  such that  $z_0/\lambda_c \approx 1$ , which gives  $F_{cr}=2m_0^2c^3/e\hbar\approx 2.6\times 10^{16}$  V/cm. Fields of this intensity are not available in terrestrial conditions. For semiconductors the corresponding probability of tunneling between the lighthole and the conduction bands is described by the exponential factor  $W = \pi \mathcal{E}_g^{3/2} m_0^{*1/2} / 2\sqrt{2} e\hbar F = (\pi/2)(z_0/\lambda_Z)$ , where  $z_0$  $=\mathcal{E}_g/eF$  is the corresponding tunneling length.<sup>21</sup> Now the critical field, at which  $z_0/\lambda_Z \approx 1$ , is  $F_Z = \mathcal{E}_g^{3/2} m_0^{*1/2} / \sqrt{2}e\hbar$ . This is of the order of  $10^5$  V/cm, which agrees with the field intensities used in semiconductor tunnel diodes.

In fact,  $\lambda_Z$  can be measured directly. We write Eq. (1) in the form

$$E = \pm \hbar u (\lambda_z^{-2} + k^2)^{1/2}.$$
 (10)

For  $k^2 > 0$  this formula describes the conduction and the light-hole bands. But for imaginary values of k there is  $k^2 < 0$  and Eq. (11) describes the dispersion in the energy gap. This region is classically forbidden but it can become accessible through quantum tunneling. Figure 1 shows the data for the dispersion in the gap of InAs, obtained by Parker and Mead<sup>22</sup> from tunneling experiments with double Schottky barriers. The solid line indicates the fit using Eq. (10). The value of  $\lambda_Z$  is determined directly by  $k_0$  for which the energy is zero:  $\lambda_Z^{-2} = k_0^2$ . The fit gives  $\lambda_Z \approx 41.5$  Å and  $u \approx 1.33 \times 10^8$  cm/s, in good agreement with the above estimation for InAs. Similar data for GaAs give  $\lambda_Z$  between 10 and 13 Å,<sup>23</sup> again in good agreement with the above estimation.

Our results should lead to two categories of observable effects. The first is related to the final electron size. For example, electron-electron interaction in narrow quantum wells or small quantum dots should be affected by the final electron size. The interaction of electrons with phonons will have

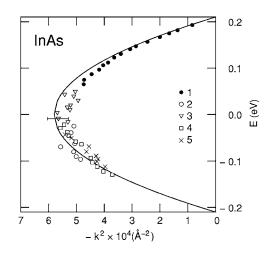


FIG. 1. Energy-wave vector dependence in the forbidden gap of InAs. Various symbols show the experimental data of Parker and Mead (Ref. 22) for five InAs samples; the solid line is a theoretical fit using Eq. (10). The determined parameters are  $\lambda_Z$ =41.5 Å and u=1.33×10<sup>8</sup> cm/s.

a nonlocal character and there will be a cutoff of the interaction for phonon wavelengths  $\lambda \leq \lambda_Z$ .<sup>24,25</sup> The effective Darwin term belongs to this group; it should be observable in shifts of the ground donor energies. The second category is associated with the question: what happens when electrons are confined to dimensions smaller than  $\lambda_{Z}$ ? It is often stated in RQM that "a measurement of the position of a particle, such as an electron, if carried out with greater precision than the Compton wavelength, would lead to pair production."<sup>26</sup> This phenomenon is related to our initial reasoning that for such an electron the uncertainty of energy is larger than the gap. It is clear, however, that the pairs created in this way can only be virtual, otherwise their recombination would lead to the production of energy out of nothing. It appears that the virtual carriers could be observed, for example, in screening effects. A different point of view is also possible. One can say, a confinement is equivalent to an infinite potential well of the width  $\Delta r < \lambda_Z$  in one or more dimensions and the electron will simply occupy the lowest energy level in such a well. One thing is certain. If an electron is confined to dimensions  $\Delta r < \lambda_Z$ , its energy (or its uncertainty) is of the order of  $\mathcal{E}_g$ , which means that the one-band description is inadequate. We are then forced to use the multiband  $\mathbf{k} \cdot \mathbf{p}$ description with all its consequences.

In our theoretical treatment we used two simplifications. The first is the use of the three-level model of band structure. This model is accurate near the band edges of NGS and it is valid up to the inflection point on the E(k) curve.<sup>27</sup> Second, we assumed that  $p_x = p_y = 0$  in the calculation of ZB and of the smearing. This was done for technical reasons, the difficulty being that the degeneracy of the valence  $\Gamma_8$  bands couples light and heavy holes. However, since the conduction band is spherical [see Eq. (1)], it is clear that our results for the direction z are approximately valid for the other two directions as well. The isotropy of the Darwin term in Eq. (5) confirms this conclusion. Our simplifying assumption  $\Delta \geq \mathcal{E}_g$ , although not quite justified for some materials, preserves the essential spin properties of electrons in NGS. We

add that another group of NGS, namely the lead salts PbTe, PbSe, and PbS, is characterized by the  $4 \times 4$  band Hamiltonian closely resembling the Dirac Hamiltonian.<sup>2,28</sup>

To summarize, we used the band structure of narrow gap semiconductors to show that, even in absence of external fields, semiconductor electrons experience the Zitterbewegung (trembling motion) with the characteristic frequency of  $\omega_Z = \mathcal{E}_g/\hbar$  and the amplitude of  $\lambda_Z = \hbar/m_0^* u$ . If the electrons are described by two-component spinors for a given energy band (which is usually the case) there is no ZB but the electrons should be treated as objects of size  $\lambda_Z$ . The magnitude of  $\lambda_Z$  in NGS can be as large as 70 Å. Observable consequences of these predictions are divided into those related to the final electron size and those resulting from the electron confinement to dimensions smaller than  $\lambda_Z$ . Such observations would lead to a deeper understanding of electrons in solids, but they would also shed light on some still unobserved predictions of relativistic quantum mechanics and quantum field theory for electrons in vacuum.

*Note added in proof.* Recently a paper has been published that also makes reference to the Zitterbewegung<sup>29</sup>. However, the Hamiltonian used in Ref. 29 is that of spin splitting (the Bychkov-Rashba mechanism) which requires structure inversion asymmetry of the system. Thus the oscillations proposed in this work do not have their correspondence for relativistic electrons in vacuum. This is in contrast to our case.

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